











SN54AHCT245, **SN74AHCT245**

SCLS233P-OCTOBER 1995-REVISED JULY 2014

SNx4AHCT245 Octal Bus Transceivers With 3-State Outputs

Features

- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.

2 Applications

- Servers
- PCs and Notebooks
- **Network Switches**
- Wearable Health and Fitness Devices
- Telecom Infrastructures
- Electronic Points of Sale

3 Description

The SNx4AHCT245 octal bus transceivers are designed for asynchronous two-way communication between data buses. These parts operate from 4.5 V to 5.5 V.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	PDIP (20)	25.40 x 6.35 mm		
	SOP (20)	12.60 x 5.30 mm		
SNx4AHCT245	SSOP (20)	7.50 x 5.30 mm		
	TVSOP (20)	5.00 x 4.40 mm		
	SOIC (20)	12.80 x 7.50 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

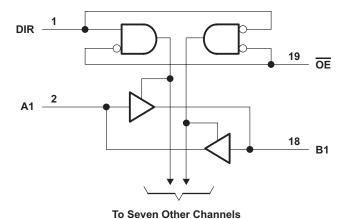




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5 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision O (August 2013) to Revision P	Page
Updated document to new TI data sheet format	1
Added Military Disclaimer to Features list.	1
Added Applications	1
Added Pin Functions table	3
Added Handling Ratings table	4
Added Thermal Information table	5
Added Typical Characteristics.	6
Added Detailed Description section	8
Added Application and Implementation section	9

CI	hanges from Revision N (March 2005) to Revision O	Page
•	Removed Ordering Information table.	1
•	Extended operating temperature range to 125°C	4

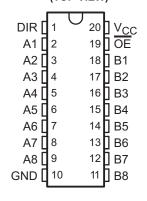
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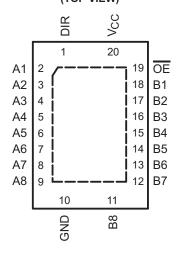


6 Pin Configuration and Functions

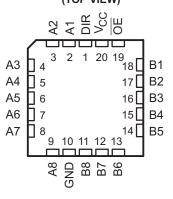
SN54AHCT245 . . . J OR W PACKAGE SN74AHCT245 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)



SN74AHCT245 . . . RGY PACKAGE (TOP VIEW)



SN54AHCT245 . . . FK PACKAGE (TOP VIEW)



Pin Functions

	PIN	1/0	DECODIDETION				
NO.	NAME	I/O	DESCRIPTION				
1	DIR	_	Direction Pin				
2	A1	I/O	A1 Input/Output				
3	A2	I/O	A2 Input/Output				
4	A3	I/O	A3 Input/Output				
5	A4	I/O	A4 Input/Output				
6	A5	I/O	A5 Input/Output				
7	A6	I/O	A6 Input/Output				
8	A7	I/O	A7 Input/Output				
9	A8	I/O	A8 Input/Output				
10	GND	_	Ground Pin				
11	B8	I/O	B8 Input/Output				
12	B7	I/O	B7 Input/Output				
13	B6	I/O	B6 Input/Output				
14	B5	I/O	B5 Input/Output				
15	B4	I/O	B4 Input/Output				
16	В3	I/O	B3 Input/Output				
17	B2	I/O	B2 Input/Output				
18	B1	I/O	B1 Input/Output				
19	ŌĒ	I	Output Enable				
20	VCC	_	Power Pin				



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

				MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	7	V		
V_{I}	Input voltage range (2)	Control inputs	-0.5	7	V	
Vo	Output voltage range (2)				V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0	Control inputs		-20	mA
I_{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$			±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}			±25	mA
	Continuous current through V_{CC} or GND	_			±75	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT	
T _{stg}	Storage temperature rang	- 65	150	°C		
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	2000	\/	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		SN54AHCT245		SN74AHC	T245	UNIT
		MIN	MAX	MIN	MIN MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level Input voltage		8.0		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	V_{CC}	0	V _{CC}	V
I _{OH}	High-level output current		-8		-8	mA
I _{OL}	Low-level output current		8		8	mA
Δt/Δν	Input Transition rise and fall rate		20		20	ns/V
T _A	Operating free-air temperature	-55	125	-40	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

				8	N74AHCT245						
	THERMAL METRIC ⁽¹⁾	DB	DGV	DW	N	NS	PW	RGY	UNIT		
			20 PINS								
$R_{\theta JA}$	Junction-to-ambient thermal resistance	96.0	116.1	79.8	51.5	77.1	102.8	35.1			
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	57.7	31.3	45.8	38.2	43.6	36.8	43.3			
$R_{\theta JB}$	Junction-to-board thermal resistance	51.2	57.6	47.4	32.4	44.6	53.8	12.9			
Ψлт	Junction-to-top characterization parameter	19.4	1.0	18.5	24.6	17.2	2.5	0.9	°C/W		
ΨЈВ	Junction-to-board characterization parameter	50.8	56.9	47.0	32.3	44.2	53.3	12.9			
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a	7.9			

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{cc}	T,	_A = 25°C	;	SN54AHC -55°C TO 1		SN74AH -40°C TO		Recomm SN74AH -40°C TO	CT245	UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
\/		$I_{OH} = -50 \mu A$	4.5 V	4.4	4.5		4.4		4.4		4.4		V
V _{OH}		$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		3.7		v
		I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1		0.1	V
V _{OL}		I _{OH} = 8 mA	4.5 V			0.36		0.44		0.44		0.44	v
I _I	OE or DIR	V _I = 5.5 V or GND	0 to 5.5 V			±0.1		±1 ⁽¹⁾		±1		±1	μA
I _{OZ}	A or B inputs (2)	V _O = V _{CC} or GND	5.5 V			±.25		±2.5		±2.5		±2.5	μA
I _{CC}		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40		40	μA
ΔI _{CC} ⁽³⁾		One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5		1.5	mA
Ci	OE or DIR	V _I = V _{CC} or GND	5 V		2.5	10				10			pF
C _{io}	A or B inputs	V _I = V _{CC} or GND	5 V		4								pF

On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC} .

STRUMENTS

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE			25°C	SN54AH -55°C TO		SN74AI -40°C T		Recomm SN74AH -40°C TC	CT245	UNIT
				TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	A or B	B or A	C 45 pF	4.5 ⁽¹⁾	7.7 ⁽¹⁾	1 ⁽¹⁾	10 ⁽¹⁾	1	8.5	1	10		
t _{PHL}	AOIB	BOIA	$C_L = 15 pF$	4.5 ⁽¹⁾	7.7 ⁽¹⁾	1 ⁽¹⁾	10 ⁽¹⁾	1	8.5	1	10	ns	
t _{PZH}	ŌĒ	A or D	C 45 pF	8.9 ⁽¹⁾	13.8 ⁽¹⁾	1 ⁽¹⁾	16 ⁽¹⁾	1	15	1	16		
t _{PZL}	OE	A OF B	A or B	$C_L = 15 pF$	8.9 ⁽¹⁾	13.8 ⁽¹⁾	1 ⁽¹⁾	16 ⁽¹⁾	1	15	1	16	ns
t _{PHZ}	ŌĒ	A or B	C _L = 15 pF	9.2 ⁽¹⁾	14.4 ⁽¹⁾	1 ⁽¹⁾	16.5 ⁽¹⁾	1	15.5	1	16.5	ns	
t _{PLZ}	OE	A or B		9.2 ⁽¹⁾	14.4 ⁽¹⁾	1 ⁽¹⁾	16.5 ⁽¹⁾	1	15.5	1	16.5	3.5	
t _{PLH}	A or B	B or A	C - 50 pF	5.3	8.7	1	11	1	9.5	1	11		
t _{PHL}	AOIB	BOIA	$C_L = 50 \text{ pF}$	5.3	8.7	1	11	1	9.5	1	11	ns	
t _{PZH}	OF.	A or B	C 50 pF	9.7	14.8	1	17	1	16	1	17		
t _{PZL}	- ŌE	AOIB	$C_L = 50 \text{ pF}$	9.7	14.8	1	17	1	16	1	17	ns	
t _{PHZ}	ŌĒ	A or B	C - 50 pF	10	15.4	1	17.5	1	16.5	1	17.5	no	
t _{PLZ}	OE .	AUID	C _L = 50 pF	10	15.4	1	17.5	1	16.5	1	17.5	ns	
t _{sk(o)}			C _L = 50 pF		1 ⁽²⁾				1			ns	

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.(2) On products compliant to MIL-PRF-38535, this parameter does not apply.

7.7 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

PARAMETER			SN74AHCT245				
	PARAMETER	MIN	TYP	MAX	UNIT		
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4		V		
$V_{IH(D)}$	High-level dynamic input voltage	2			V		
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V		

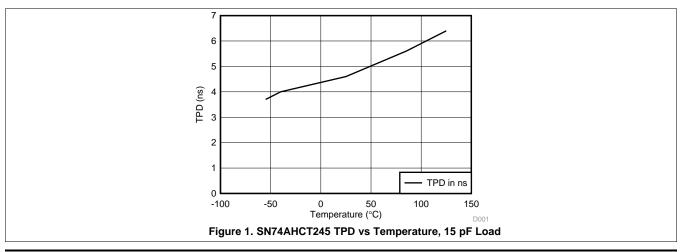
⁽¹⁾ Characteristics are for surface-mount packages only.

7.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	NDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	13	pF

7.9 Typical Characteristics

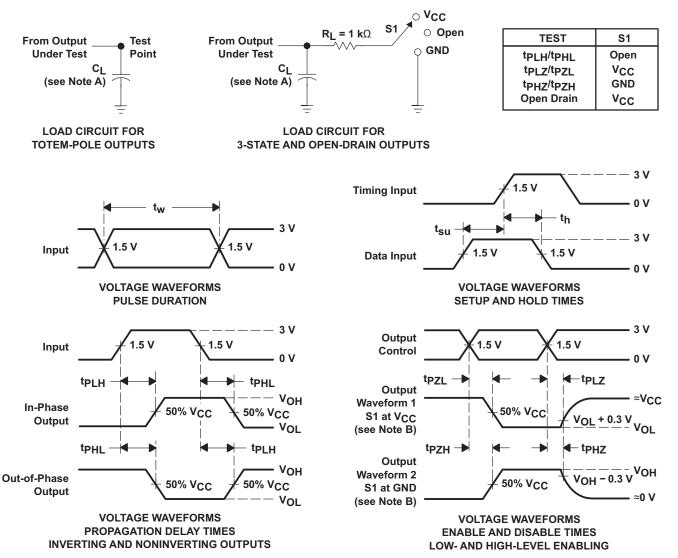


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8 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output
 - Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 3 ns. $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

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9 Detailed Description

9.1 Overview

The SNx7ACHT245 octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements. The SNx4AHCT245 devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction—control (DIR) input. The output-enable ($\overline{\text{OE}}$) input can be used to disable the device so that the buses effectively are isolated. To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

9.2 Functional Block Diagram

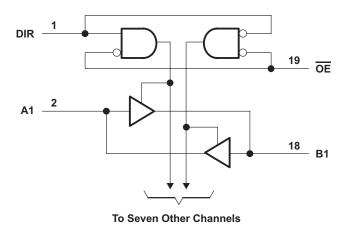


Figure 3. Logic Diagram (Positive Logic)

9.3 Feature Description

- V_{CC} is optimized at 5 V
- Allows up voltage translation from 3.3 V to 5 V
 - Inputs Accept V_{IH} levels of 2 V
- Slow edge rates minimize output ringing

9.4 Device Functional Modes

Table 1. Function Table (Each Transceiver)

INP	UTS	OPERATION					
OE	DIR	OPERATION					
L	L	B data to A bus					
L	Н	A data to B bus					
Н	Χ	Isolation					

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10 Application and Implementation

10.1 Application Information

The SN74AHCT245 is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8 V V_{IL} and 2 V V_{IH} . This feature makes it ideal for translating up from 3.3 V to 5 V. The figure below shows this type of translation.

10.2 Typical Application

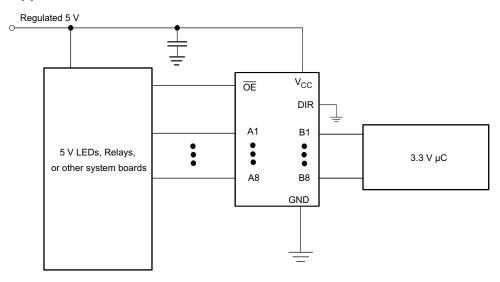


Figure 4. Typical Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

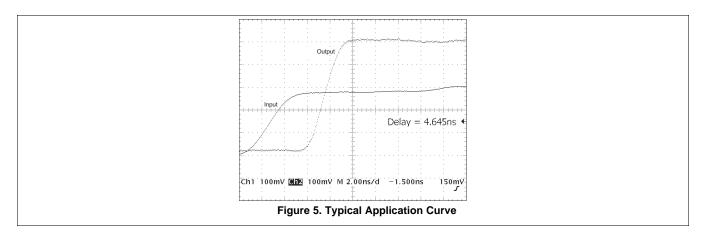
- Recommended input conditions
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}
- · Recommend output conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}

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Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ f is recommended; if there are multiple VCC pins, then 0.01 μ f or 0.022 μ f is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ f and a 1 μ f are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 6 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or $V_{\rm CC}$, whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

12.2 Layout Example

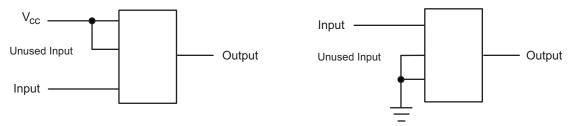


Figure 6. Layout Diagram

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13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHCT245	Click here	Click here	Click here	Click here	Click here
SN74AHCT245	Click here	Click here	Click here	Click here	Click here

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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13-Oct-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9681901Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9681901Q2A SNJ54AHCT 245FK	Samples
5962-9681901QRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9681901QR A SNJ54AHCT245J	Samples
5962-9681901QSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9681901QS A SNJ54AHCT245W	Samples
SN74AHCT245DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245DBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245DGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT245N	Samples
SN74AHCT245NSR	ACTIVE	so	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245	Samples
SN74AHCT245PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWG4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWRG3	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB245	Samples
SN74AHCT245RGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HB245	Samples



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54AHCT245FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9681901Q2A SNJ54AHCT 245FK	Samples
SNJ54AHCT245J	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9681901QR A SNJ54AHCT245J	Samples
SNJ54AHCT245W	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9681901QS A SNJ54AHCT245W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54AHCT245, SN74AHCT245:

Catalog: SN74AHCT245

• Military : SN54AHCT245

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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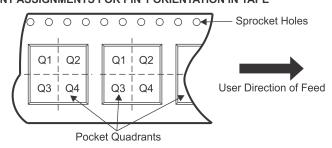
TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
ľ	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

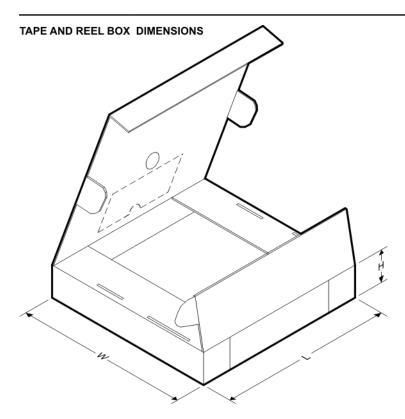


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT245DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHCT245DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT245DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74AHCT245NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHCT245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHCT245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT245PWRG3	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT245PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHCT245RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT245DBR	SSOP	DB	20	2000	853.0	449.0	35.0
SN74AHCT245DGVR	TVSOP	DGV	20	2000	853.0	449.0	35.0
SN74AHCT245DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT245NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AHCT245PWR	TSSOP	PW	20	2000	853.0	449.0	35.0
SN74AHCT245PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHCT245PWRG3	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHCT245PWRG4	TSSOP	PW	20	2000	853.0	449.0	35.0
SN74AHCT245RGYR	VQFN	RGY	20	3000	853.0	449.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9681901Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
SN74AHCT245DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74AHCT245N	N	PDIP	20	20	506	13.97	11230	4.32
SN74AHCT245PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74AHCT245PWG4	PW	TSSOP	20	70	530	10.2	3600	3.5
SNJ54AHCT245FK	FK	LCCC	20	1	506.98	12.06	2030	NA

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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